

DS90CR218 +3.3V Rising Edge Data Strobe LVDS 21-Bit Channel Link Receiver - 75 MHz

Check for Samples: [DS90CR218](#)

FEATURES

- 20 to 75 MHz Shift Clock Support
- 50% Duty cycle on receiver output clock
- Best-in-Class Set & Hold Times on TxINPUTs and RxOUTPUTs
- Low Power Consumption
- Tx + Rx Powerdown Mode <math><400\mu\text{W}</math> (max)
- $\pm 1\text{V}$ Common-Mode Range (around +1.2V)
- Narrow Bus Reduces Cable Size and Cost
- Up to 1.575 Gbps Throughput
- Up to 197 Mbytes/sec Bandwidth
- 345 mV (typ) Swing LVDS Devices for Low EMI
- PLL Requires No External Components
- Rising Edge Data Strobe
- Compatible with TIA/EIA-644 LVDS Standard
- Low Profile 48-Lead TSSOP Package

DESCRIPTION

The DS90CR217 transmitter converts 21 bits of CMOS/TTL data into three LVDS (Low Voltage Differential Signaling) data streams. A phase-locked transmit clock is transmitted in parallel with the data streams over a fourth LVDS link. Every cycle of the transmit clock 21 bits of input data are sampled and transmitted. The DS90CR218 receiver converts the three LVDS data streams back into 21 bits of CMOS/TTL data. At a transmit clock frequency of 75 MHz, 21 bits of TTL data are transmitted at a rate of 525 Mbps per LVDS data channel. Using a 75 MHz clock, the data throughput is 1.575 Gbit/s (197 Mbytes/sec).

Complete specifications for the DS90CR217 are located in the DS90CR217/DS90CR218A datasheet. The DS90CR217 supports clock rates from 20 to 85 MHz.

This chipset is an ideal means to solve EMI and cable size problems associated with wide, high-speed TTL interfaces.

BLOCK DIAGRAM

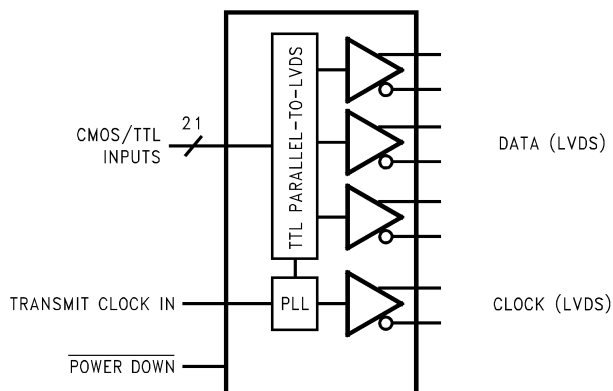


Figure 1. DS90CR217
See Package Number DGG-48 (TSSOP)

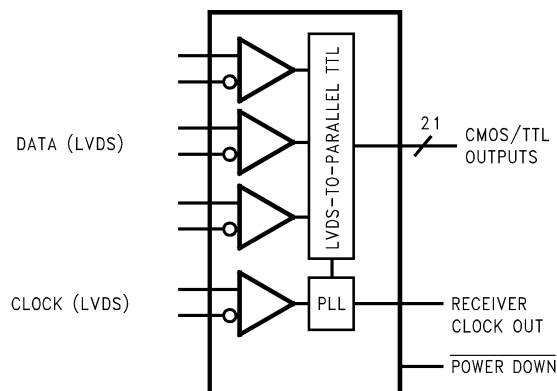


Figure 2. DS90CR218
See Package Number DGG-48 (TSSOP)



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

All trademarks are the property of their respective owners.

Pin Diagram

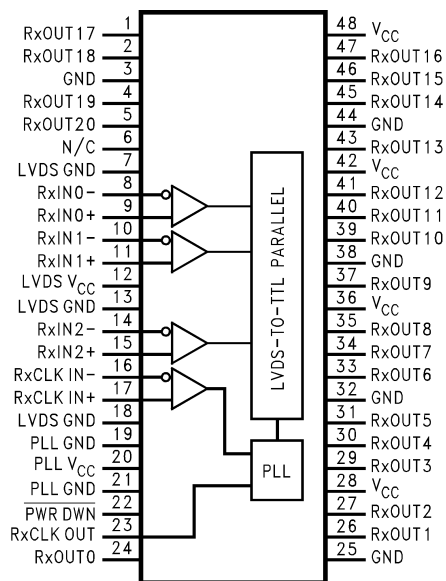
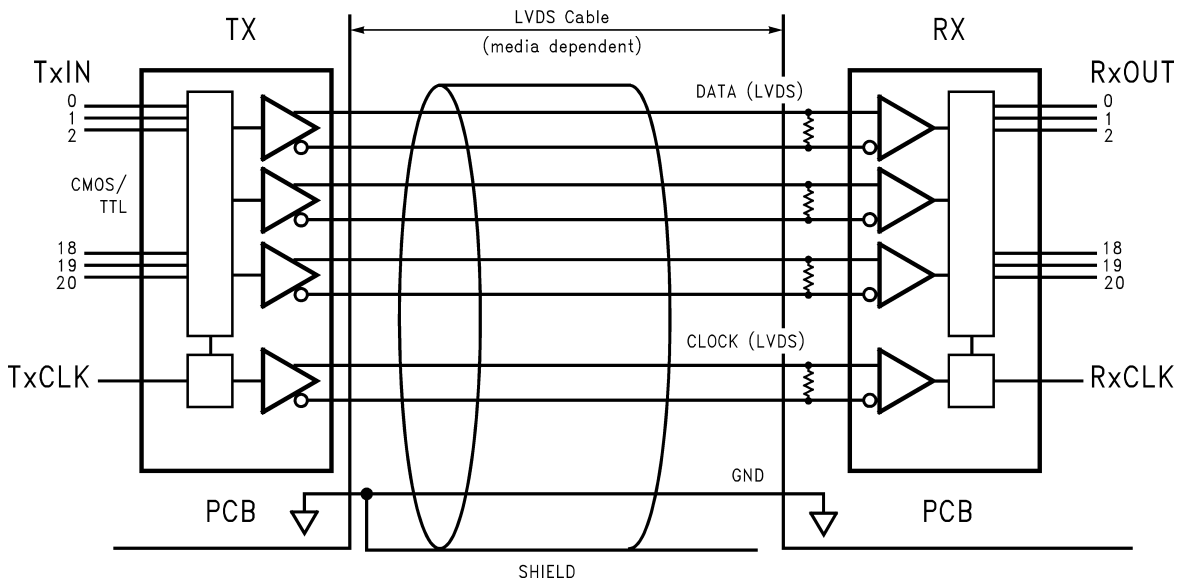


Figure 3. DS90CR218

Typical Application



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

Absolute Maximum Ratings⁽¹⁾⁽²⁾

Supply Voltage (V_{CC})		-0.3V to +4V
CMOS/TTL Input Voltage		-0.5V to ($V_{CC} + 0.3V$)
CMOS/TTL Output Voltage		-0.3V to ($V_{CC} + 0.3V$)
LVDS Receiver Input Voltage		-0.3V to ($V_{CC} + 0.3V$)
Junction Temperature		+150°C
Storage Temperature Range		-65°C to +150°C
Lead Temperature (Soldering, 4 sec.)		+260°C
Maximum Package Power Dissipation @ +25°C	DGG0048A (TSSOP) Package DS90CR218	1.89 W
Package Derating DS90CR218		15 mW/°C above +25°C
ESD Rating	(HBM, 1.5k Ω , 100pF)	> 7kV
	(EIAJ, 0 Ω , 200pF)	> 700V
Latch Up Tolerance @ 25°C		> ± 300 mA

- (1) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/ Distributors for availability and specifications.
- (2) "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the device should be operated at these limits. "Electrical Characteristics" specify conditions for device operation.

Recommended Operating Conditions

	Min	Nom	Max	Units
Supply Voltage (V_{CC})	3.0	3.3	3.6	V
Operating Free Air Temperature (T_A)	-10	+25	+70	°C
Receiver Input Range	0		2.4	V
Supply Noise Voltage (V_{CC})			100	mV _{PP}

Electrical Characteristics

Over recommended operating supply and temperature ranges unless otherwise specified

Symbol	Parameter	Conditions	Min	Typ ⁽¹⁾	Max	Units
CMOS/TTL DC SPECIFICATIONS						
V_{IH}	High Level Input Voltage		2.0		V_{CC}	V
V_{IL}	Low Level Input Voltage		GND		0.8	V
V_{OH}	High Level Output Voltage	$I_{OH} = -0.4$ mA	2.7	3.3		V
V_{OL}	Low Level Output Voltage	$I_{OL} = 2$ mA		0.06	0.3	V
V_{CL}	Input Clamp Voltage	$I_{CL} = -18$ mA		-0.79	-1.5	V
I_{IN}	Input Current	$V_{IN} = 0.4V, 2.5V$ or V_{CC}		+1.8	+10	μ A
		$V_{IN} = GND$	-10	0		μ A
I_{OS}	Output Short Circuit Current	$V_{OUT} = 0V$		-60	-120	mA
LVDS RECEIVER DC SPECIFICATIONS						
V_{TH}	Differential Input High Threshold	$V_{CM} = +1.2V$			+100	mV
V_{TL}	Differential Input Low Threshold		-100			mV
I_{IN}	Input Current	$V_{IN} = +2.4V, V_{CC} = 3.6V$			± 10	μ A
		$V_{IN} = 0V, V_{CC} = 3.6V$			± 10	μ A

- (1) Typical values are given for $V_{CC} = 3.3V$ and $T_A = +25^\circ C$.

Electrical Characteristics (continued)

Over recommended operating supply and temperature ranges unless otherwise specified

Symbol	Parameter	Conditions	Min	Typ ⁽¹⁾	Max	Units	
RECEIVER SUPPLY CURRENT⁽²⁾							
I _{CCRW}	Receiver Supply Current Worst Case	C _L = 8 pF, Worst Case Pattern (Figure 4 Figure 5)	f = 33 MHz		49	60	mA
			f = 40 MHz		53	65	mA
			f = 66 MHz		78	95	mA
			f = 75 MHz		90	105	mA
I _{CCRZ}	Receiver Supply Current Power Down	PWR DWN = Low Receiver Outputs Stay Low during Powerdown Mode		15	55	μA	

(2) Current into device pins is defined as positive. Current out of device pins is defined as negative. Voltages are referenced to ground unless otherwise specified (except V_{TH} and V_{TL}).

Receiver Switching Characteristics

Over recommended operating supply and temperature ranges unless otherwise specified

Symbol	Parameter	Conditions	Min	Typ ⁽¹⁾	Max	Units
CLHT	CMOS/TTL Low-to-High Transition Time (Figure 5)			2.0	3.5	ns
CHLT	CMOS/TTL High-to-Low Transition Time (Figure 5)			1.8	3.5	ns
RSPos0	Receiver Input Strobe Position for Bit 0 (Figure 11)	f = 75 MHz	0.58	0.95	1.32	ns
RSPos1	Receiver Input Strobe Position for Bit 1		2.49	2.86	3.23	ns
RSPos2	Receiver Input Strobe Position for Bit 2		4.39	4.76	5.13	ns
RSPos3	Receiver Input Strobe Position for Bit 3		6.30	6.67	7.04	ns
RSPos4	Receiver Input Strobe Position for Bit 4		8.20	8.57	8.94	ns
RSPos5	Receiver Input Strobe Position for Bit 5		10.11	10.48	10.85	ns
RSPos6	Receiver Input Strobe Position for Bit 6		12.01	12.38	12.75	ns
RSKM	Receiver Skew Margin (when used with DS90CR217) ⁽²⁾ (Figure 12)	f = 75 MHz	380			ps
RCOP	RxCLK OUT Period (Figure 6)		13.33	T	50	ns
RCOH	RxCLK OUT High Time (Figure 6)	f = 75 MHz	3.6	5	6.0	ns
RCOL	RxCLK OUT Low Time (Figure 6)		3.6	5	6.0	ns
RSRC	RxOUT Setup to RxCLK OUT (Figure 6)		3.5			ns
RHRC	RxOUT Hold to RxCLK OUT (Figure 6)		3.5			ns
RCCD	RxCLK IN to RxCLK OUT Delay @ 25°C, V _{CC} = 3.3V ⁽³⁾ (Figure 7)		3.4	5.0	7.3	ns
RPLLS	Receiver Phase Lock Loop Set (Figure 8)				10	ms
RPDD	Receiver Powerdown Delay (Figure 10)				1	μs

(1) Typical values are given for V_{CC} = 3.3V and T_A = +25°C.

(2) Receiver Skew Margin is defined as the valid data sampling region at the receiver inputs. This margin takes into account the transmitter pulse positions (min and max) and the receiver input setup and hold time (internal data sampling window). This margin allows LVDS interconnect skew, inter-symbol interference (both dependent on type/length of cable), and source clock jitter less than 250 ps.

(3) Total latency for the channel link chipset is a function of clock period and gate delays through the transmitter (TCCD) and receiver (RCCD). The total latency for the 217/287 transmitter and 218/288 receiver is: (T + TCCD) + (2*T + RCCD), where T = Clock period.

AC Timing Diagrams

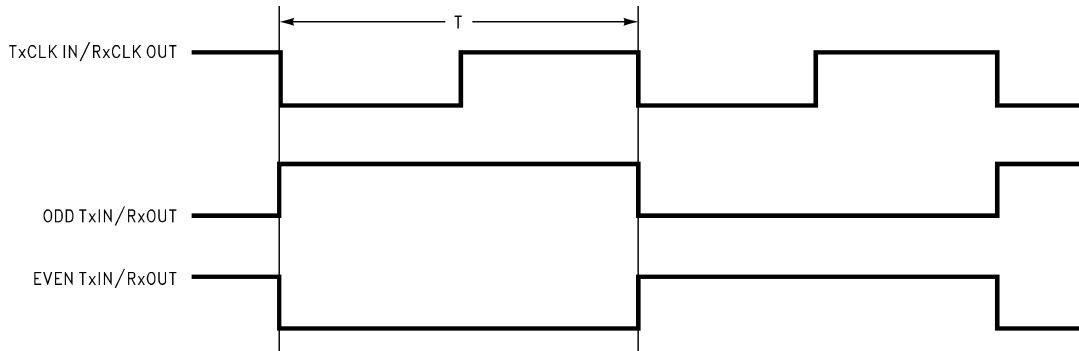


Figure 4. "Worst Case" Test Pattern

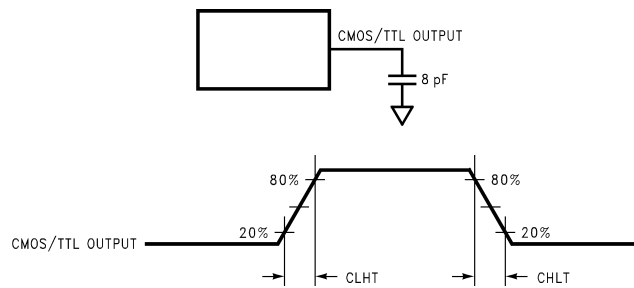


Figure 5. DS90CR218 (Receiver) CMOS/TTL Output Load and Transition Times

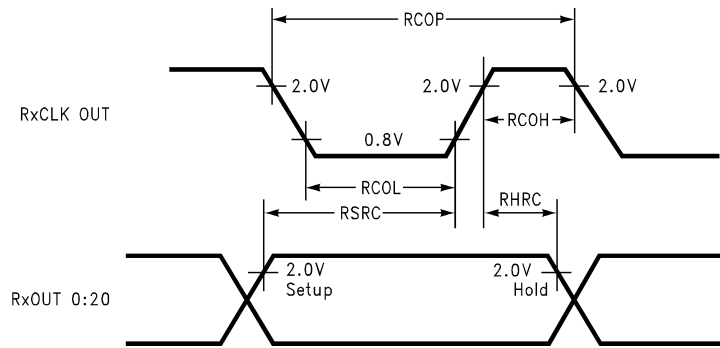


Figure 6. DS90CR218 (Receiver) Setup/Hold and High/Low Times

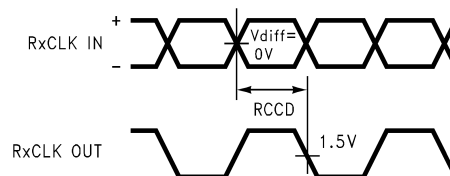


Figure 7. DS90CR218 (Receiver) Clock In to Clock Out Delay

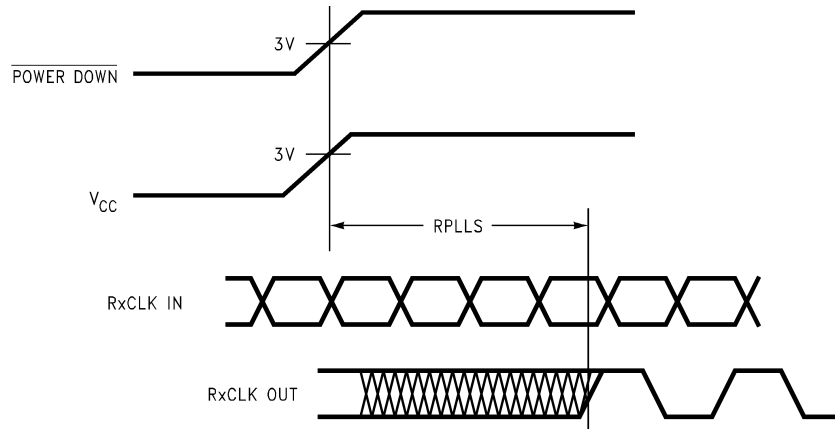


Figure 8. DS90CR218 (Receiver) Phase Lock Loop Set Time

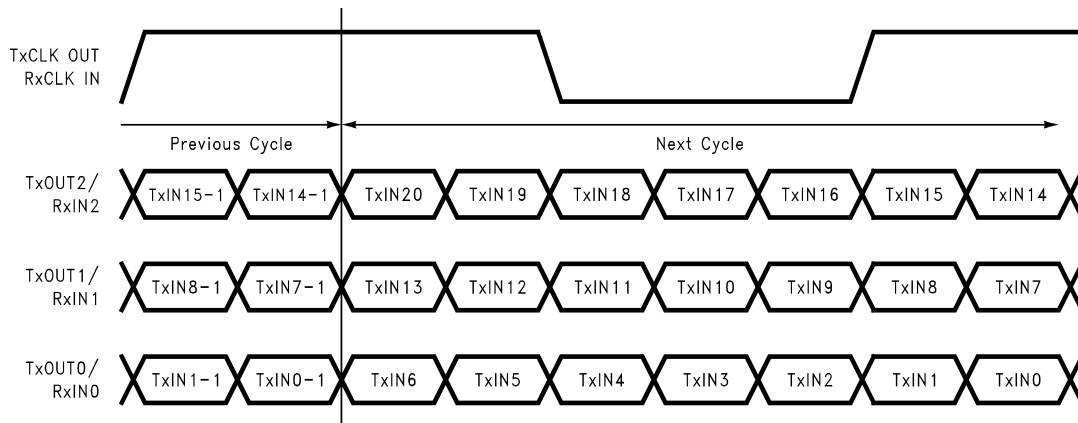


Figure 9. 21 Parallel TTL Data Inputs Mapped to LVDS Outputs (DS90CR217)

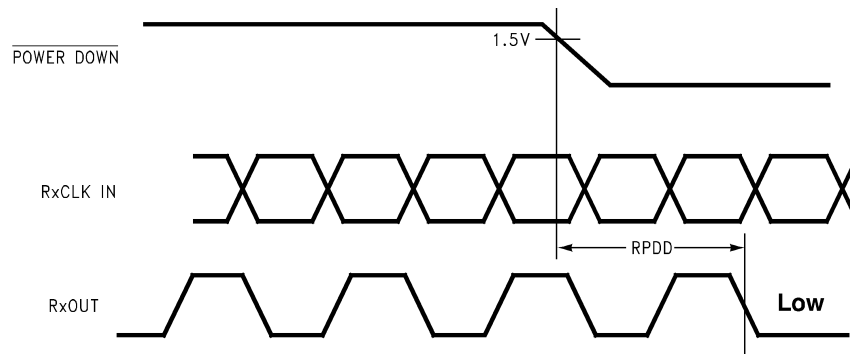


Figure 10. Receiver Powerdown Delay

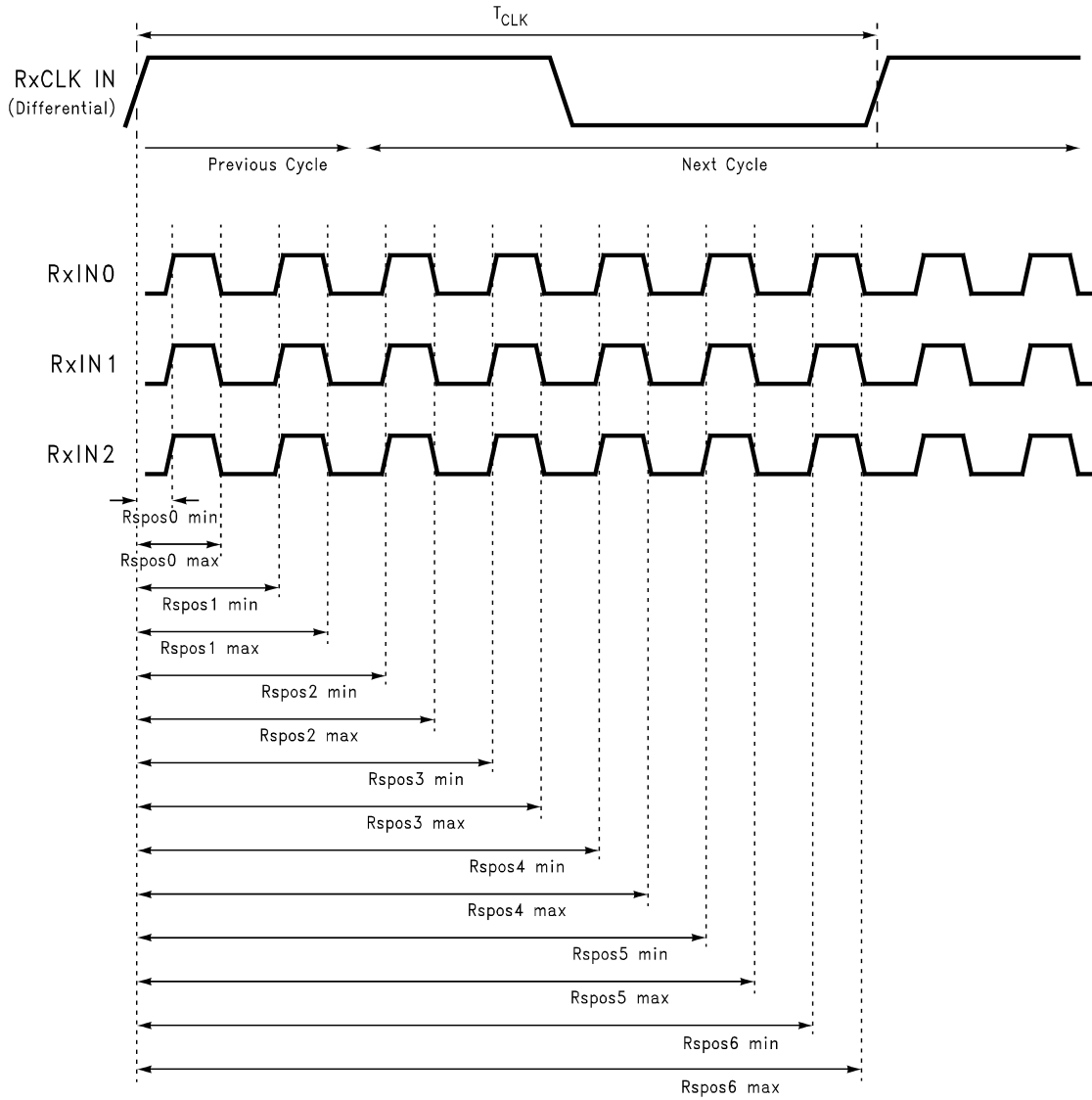
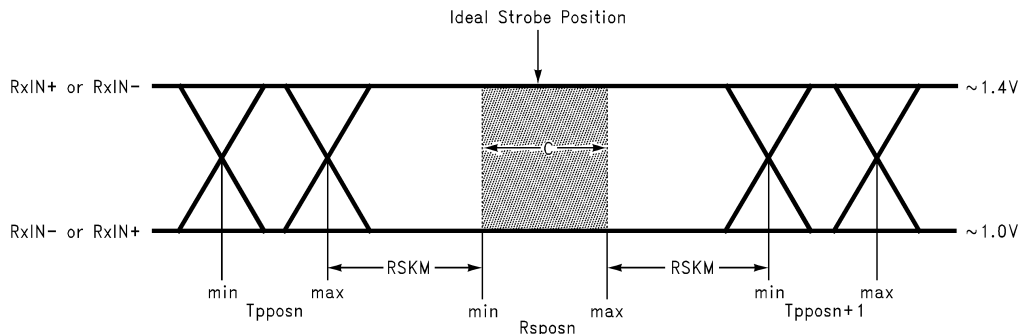


Figure 11. Receiver LVDS Input Strobe Position



C—Setup and Hold Time (Internal data sampling window) defined by Rspostn (receiver input strobe position) min and max

Tpposn—Transmitter output pulse position (min and max)

$RSKM \geq \text{Cable Skew (type, length)} + \text{Source Clock Jitter (cycle to cycle)}^{(1)} + \text{ISI (Inter-symbol interference)}^{(2)}$

Cable Skew—typically 10 ps–40 ps per foot, media dependent

- (1) Cycle-to-cycle jitter is less than 250 ps at 75MHz
 (2) ISI is dependent on interconnect length; may be zero

Figure 12. Receiver LVDS Input Skew Margin (DS90CR217/DS90CR218)

DS90CR218 PIN DESCRIPTION—Channel Link Receiver

Pin Name	I/O	No.	Description
RxIN+	I	3	Positive LVDS differential data inputs. ⁽¹⁾
RxIN-	I	3	Negative LVDS differential data inputs. ⁽¹⁾
RxOUT	O	21	TTL level data outputs.
RxCLK IN+	I	1	Positive LVDS differential clock input.
RxCLK IN-	I	1	Negative LVDS differential clock input.
RxCLK OUT	O	1	TTL level clock output. The rising edge acts as data strobe. Pin name RxCLK OUT.
$\overline{\text{PWR DWN}}$	I	1	TTL level input. When asserted (low input) the receiver outputs are low.
V _{CC}	I	4	Power supply pins for TTL outputs.
GND	I	5	Ground pins for TTL outputs.
PLL V _{CC}	I	1	Power supply for PLL.
PLL GND	I	2	Ground pin for PLL.
LVDS V _{CC}	I	1	Power supply pin for LVDS inputs.
LVDS GND	I	3	Ground pins for LVDS inputs.

- (1) These receivers have input failsafe bias circuitry to guarantee a stable receiver output for floating or terminated receiver inputs. Under these conditions receiver inputs will be in a HIGH state. If a clock signal is present, outputs will all be HIGH; if the clock input is also floating/terminated outputs will remain in the last valid state. A floating/terminated clock input will result in a LOW clock output.

APPLICATIONS INFORMATION

The DS90CR217 and DS90CR218 are backward compatible with the existing 5V Channel Link transmitter/receiver pair (DS90CR213, DS90CR214). To upgrade from a 5V to a 3.3V system the following must be addressed:

1. Change 5V power supply to 3.3V. Provide this supply to the V_{CC} , LVDS V_{CC} and PLL V_{CC} .
2. Transmitter input and control inputs except 3.3V TTL/CMOS levels. They are not 5V tolerant.
3. The receiver powerdown feature when enabled will lock receiver output to a logic low. However, the 5V/66 MHz receiver maintain the outputs in the previous state when powerdown occurred.

The Channel Link devices are intended to be used in a wide variety of data transmission applications. Depending upon the application the interconnecting media may vary. For example, for lower data rate (clock rate) and shorter cable lengths (< 2m), the media electrical performance is less critical. For higher speed/long distance applications the media's performance becomes more critical. Certain cable constructions provide tighter skew (matched electrical length between the conductors and pairs). Twin-coax for example, has been demonstrated at distances as great as 5 meters and with the maximum data transfer of 1.58 Gbit/s. Additional applications information can be found in the following Interface Application Notes:

AN = ####	Topic
AN-1041 (SNLA218)	Introduction to Channel Link
AN-1108 (SNLA008)	PCB Design Guidelines for LVDS and Link Devices
AN-806 (SNLA026)	Transmission Line Theory
AN-905 (SNLA035)	Transmission Line Calculations and Differential Impedance
AN-916 (SNLA219)	Cable Information

CABLES: A cable interface between the transmitter and receiver needs to support the differential LVDS pairs. The 21-bit CHANNEL LINK chipset (DS90CR217/218) requires four pairs of signal wires and the 28-bit CHANNEL LINK chipset (DS90CR287/288) requires five pairs of signal wires. The ideal cable/connector interface would have a constant 100Ω differential impedance throughout the path. It is also recommended that cable skew remain below 130ps (@ 75 MHz clock rate) to maintain a sufficient data sampling window at the receiver.

In addition to the four or five cable pairs that carry data and clock, it is recommended to provide at least one additional conductor (or pair) which connects ground between the transmitter and receiver. This low impedance ground provides a common-mode return path for the two devices. Some of the more commonly used cable types for point-to-point applications include flat ribbon, flex, twisted pair and Twin-Coax. All are available in a variety of configurations and options. Flat ribbon cable, flex and twisted pair generally perform well in short point-to-point applications while Twin-Coax is good for short and long applications. When using ribbon cable, it is recommended to place a ground line between each differential pair to act as a barrier to noise coupling between adjacent pairs. For Twin-Coax cable applications, it is recommended to utilize a shield on each cable pair. All extended point-to-point applications should also employ an overall shield surrounding all cable pairs regardless of the cable type. This overall shield results in improved transmission parameters such as faster attainable speeds, longer distances between transmitter and receiver and reduced problems associated with EMS or EMI.

The high-speed transport of LVDS signals has been demonstrated on several types of cables with excellent results. However, the best overall performance has been seen when using Twin-Coax cable. Twin-Coax has very low cable skew and EMI due to its construction and double shielding. All of the design considerations discussed here and listed in the supplemental application notes provide the subsystem communications designer with many useful guidelines. It is recommended that the designer assess the tradeoffs of each application thoroughly to arrive at a reliable and economical cable solution.

BOARD LAYOUT: To obtain the maximum benefit from the noise and EMI reductions of LVDS, attention should be paid to the layout of differential lines. Lines of a differential pair should always be adjacent to eliminate noise interference from other signals and take full advantage of the noise canceling of the differential signals. The board designer should also try to maintain equal length on signal traces for a given differential pair. As with any high-speed design, the impedance discontinuities should be limited (reduce the numbers of vias and no 90 degree angles on traces). Any discontinuities which do occur on one signal line should be mirrored in the other line of the differential pair. Care should be taken to ensure that the differential trace impedance match the

differential impedance of the selected physical media (this impedance should also match the value of the termination resistor that is connected across the differential pair at the receiver's input). Finally, the location of the CHANNEL LINK TxOUT/RxIN pins should be as close as possible to the board edge so as to eliminate excessive pcb runs. All of these considerations will limit reflections and crosstalk which adversely effect high frequency performance and EMI.

TERMINATION: Use of current mode drivers requires a terminating resistor across the receiver inputs. The CHANNEL LINK chipset will normally require a single 100Ω resistor between the true and complement lines on each differential pair of the receiver input. The actual value of the termination resistor should be selected to match the differential mode characteristic impedance (90Ω to 120Ω typical) of the cable. Figure 13 shows an example. No additional pull-up or pull-down resistors are necessary as with some other differential technologies such as PECL. Surface mount resistors are recommended to avoid the additional inductance that accompanies leaded resistors. These resistors should be placed as close as possible to the receiver input pins to reduce stubs and effectively terminate the differential lines.

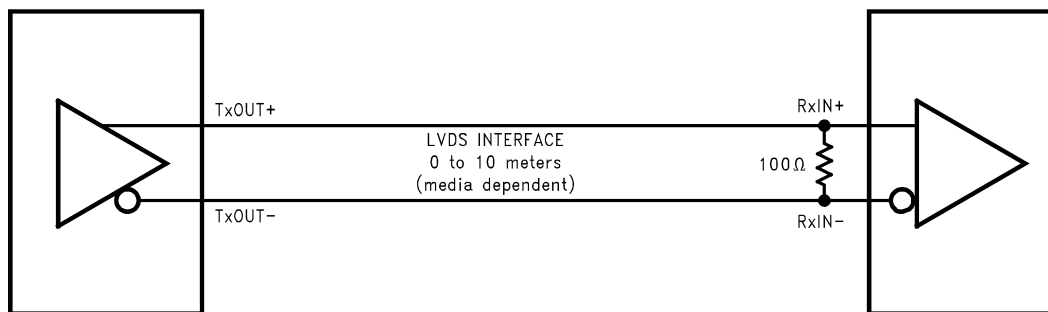


Figure 13. LVDS Serialized Link Termination

DECOUPLING CAPACITORS: Bypassing capacitors are needed to reduce the impact of switching noise which could limit performance. For a conservative approach three parallel-connected decoupling capacitors (Multi-Layered Ceramic type in surface mount form factor) between each V_{CC} and the ground plane(s) are recommended. The three capacitor values are 0.1 μF, 0.01 μF and 0.001 μF. An example is shown in Figure 14. The designer should employ wide traces for power and ground and ensure each capacitor has its own via to the ground plane. If board space is limiting the number of bypass capacitors, the PLL V_{CC} should receive the most filtering/bypassing. Next would be the LVDS V_{CC} pins and finally the logic V_{CC} pins.

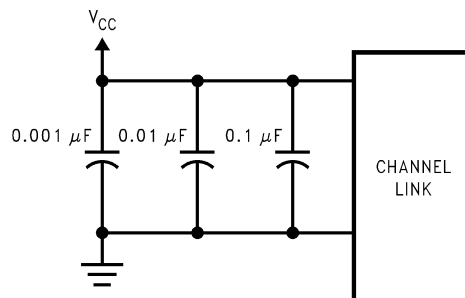


Figure 14. CHANNEL LINK Decoupling Configuration

CLOCK JITTER: The CHANNEL LINK devices employ a PLL to generate and recover the clock transmitted across the LVDS interface. The width of each bit in the serialized LVDS data stream is one-seventh the clock period. For example, a 75 MHz clock has a period of 13.33 ns which results in a data bit width of 1.90 ns. Differential skew (Δt within one differential pair), interconnect skew (Δt of one differential pair to another) and clock jitter will all reduce the available window for sampling the LVDS serial data streams. Care must be taken to ensure that the clock input to the transmitter be a clean low noise signal. Individual bypassing of each V_{CC} to ground will minimize the noise passed on to the PLL, thus creating a low jitter LVDS clock. These measures provide more margin for channel-to-channel skew and interconnect skew as a part of the overall jitter/skew budget.

COMMON-MODE vs. DIFFERENTIAL MODE NOISE MARGIN: The typical signal swing for LVDS is 300 mV centered at +1.2V. The CHANNEL LINK receiver supports a 100 mV threshold therefore providing approximately 200 mV of differential noise margin. Common-mode protection is of more importance to the system's operation due to the differential data transmission. LVDS supports an input voltage range of Ground to +2.4V. This allows for a $\pm 1.0V$ shifting of the center point due to ground potential differences and common-mode noise.

TRANSMITTER INPUT CLOCK: The transmitter input clock must always be present when the device is enabled ($\overline{\text{PWR DWN}} = \text{HIGH}$). If the clock is stopped, the $\overline{\text{PWR DWN}}$ pin must be used to disable the PLL. The $\overline{\text{PWR DWN}}$ pin must be held low until after the input clock signal has been reapplied. This will ensure a proper device reset and PLL lock to occur.

POWER SEQUENCING AND POWERDOWN MODE: Outputs of the CHANNEL LINK transmitter remain in TRI-STATE until the power supply reaches 2V. Clock and data outputs will begin to toggle 10 ms after V_{CC} has reached 3V and the Powerdown pin is above 1.5V. Either device may be placed into a powerdown mode at any time by asserting the Powerdown pin (active low). Total power dissipation for each device will decrease to 5 μW (typical).

The transmitter input clock may be applied prior to powering up and enabling the transmitter. The transmitter input clock may also be applied after power up; however, the use of the $\overline{\text{PWR DWN}}$ pin is required. Do not power up and enable ($\overline{\text{PWR DWN}} = \text{HIGH}$) the transmitter without a valid clock signal applied to the TxCLK IN pin.

The CHANNEL LINK chipset is designed to protect itself from accidental loss of power to either the transmitter or receiver. If power to the transmit board is lost, the receiver clocks (input and output) stop. The data outputs (RxOUT) retain the states they were in when the clocks stopped. When the receiver board loses power, the receiver inputs are shorted to V_{CC} through an internal diode. Current is limited (5 mA per input) by the fixed current mode drivers, thus avoiding the potential for latchup when powering the device.

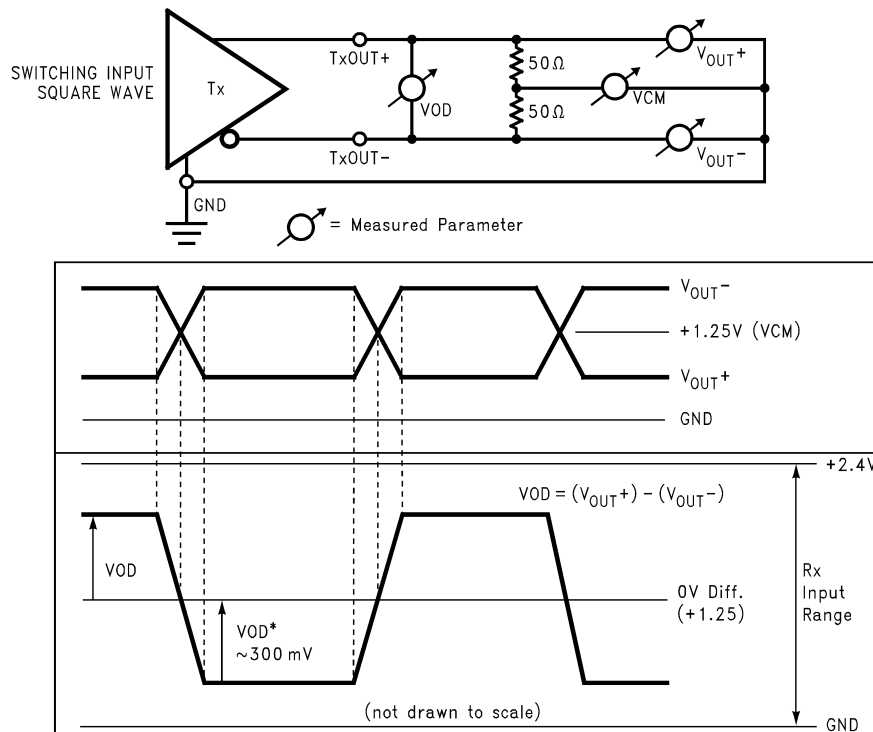


Figure 15. Single-Ended and Differential Waveforms

REVISION HISTORY

Changes from Revision D (April 2013) to Revision E	Page
• Changed layout of National Data Sheet to TI format	11

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have **not** been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products

Audio	www.ti.com/audio
Amplifiers	amplifier.ti.com
Data Converters	dataconverter.ti.com
DLP® Products	www.dlp.com
DSP	dsp.ti.com
Clocks and Timers	www.ti.com/clocks
Interface	interface.ti.com
Logic	logic.ti.com
Power Mgmt	power.ti.com
Microcontrollers	microcontroller.ti.com
RFID	www.ti-rfid.com
OMAP Applications Processors	www.ti.com/omap
Wireless Connectivity	www.ti.com/wirelessconnectivity

Applications

Automotive and Transportation	www.ti.com/automotive
Communications and Telecom	www.ti.com/communications
Computers and Peripherals	www.ti.com/computers
Consumer Electronics	www.ti.com/consumer-apps
Energy and Lighting	www.ti.com/energy
Industrial	www.ti.com/industrial
Medical	www.ti.com/medical
Security	www.ti.com/security
Space, Avionics and Defense	www.ti.com/space-avionics-defense
Video and Imaging	www.ti.com/video

TI E2E Community

e2e.ti.com